

Specifications	
Part Number	2N7002DWH6327XTSA1
Manufacturer	Initial State Technologies, Inc.
Description	MOSFET 2N-CH 60V 0.3A SOT363
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2879 pcs Stock
Voltage - Test	20pF @ 25V
Voltage - Breakdown	PG-SOT363-6
Vgs(th) (Max) @ Id	3 Ohm @ 500mA, 10V
Series	OptiMOS™
RoHS Status	Tape & Reel (TR)
Rds On (Max) @ Id, Vgs	300mA
Power - Max	500mW
Polarization	6-VSSOP, SC-88, SOT-363
Other Names	2N7002DW H6327
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Moisture Sensitivity Level (MSL)	1 (Unlimited)
Manufacturer Standard Lead Time	8 Weeks
Manufacturer Part Number	2N7002DWH6327XTSA1
Input Capacitance (Ciss) (Max) @ Vds	0.6nC @ 10V
Gate Charge (Qg) (Max) @ Vgs	2.5V @ 250µA
FET Feature	2 N-Channel (Dual)
Expanded Description	Mosfet Array 2 N-Channel (Dual) 60V 300mA 500mW
Drain to Source Voltage (Vdss)	Logic Level Gate
Description	MOSFET 2N-CH 60V 0.3A SOT363
Current - Continuous Drain (Id) @ 25°C	60V

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More

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